

# DMZ1521E



## Depletion-Mode Power MOSFET

### General Features

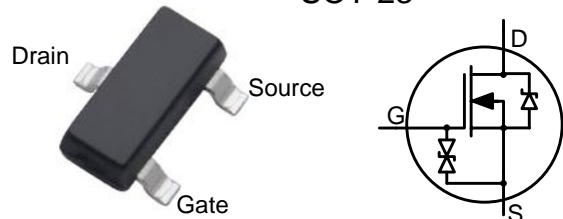
- ESD improved Capability
- Depletion Mode (Normally On)
- Proprietary Advanced Planar Technology
- Rugged Polysilicon Gate Cell Structure
- Fast Switching Speed
- RoHS Compliant
- Halogen-free available

$BV_{DSX}$	$R_{DS(ON)}$ (Max.)	$I_{DSS,min}$
150V	15 $\Omega$	200mA

### Applications

- Synchronous Rectification
- Normally-on Switches
- Linear Amplifier
- Converters
- Constant Current Source
- Telecom

SOT-23



### Ordering Information

Part Number	Package	Marking	Remark
DMZ1521E	SOT-23	1521	Halogen Free

### Absolute Maximum Ratings

$T_A=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	DMZ1521E	Unit
$V_{DSX}$	Drain-to-Source Voltage <sup>[1]</sup>	150	V
$V_{DGX}$	Drain-to-Gate Voltage <sup>[1]</sup>	150	V
$I_D$	Continuous Drain Current	0.2	A
$I_{DM}$	Pulsed Drain Current <sup>[2]</sup>	0.6	
$P_D$	Power Dissipation	0.50	W
$V_{GS}$	Gate-to-Source Voltage	$\pm 20$	V
$T_L$	Soldering Temperature Distance of 1.6mm from case for 10 seconds	300	$^{\circ}\text{C}$
$T_J$ and $T_{STG}$	Operating and Storage Temperature Range	-55 to 150	

Caution: Stresses greater than those listed in the "Absolute Maximum Ratings" may cause permanent damage to the device.

### Thermal Characteristics

Symbol	Parameter	DMZ1521E	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	250	K/W

## Electrical Characteristics

### OFF Characteristics

 $T_A = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
$BV_{DSX}$	Drain-to-Source Breakdown Voltage	150	--	--	V	$V_{GS} = -15\text{V}$ , $I_D = 250\mu\text{A}$
$I_{D(OFF)}$	Drain-to-Source Leakage Current	--	--	10	$\mu\text{A}$	$V_{DS} = 150\text{V}$ , $V_{GS} = -15\text{V}$
		--	--	1.0	mA	$V_{DS} = 150\text{V}$ , $V_{GS} = -15\text{V}$ $T_J = 125^\circ\text{C}$
$I_{GSS}$	Gate-to-Source Leakage Current	--	--	20	$\mu\text{A}$	$V_{GS} = +20\text{V}$ , $V_{DS} = 0\text{V}$
		--	--	-20		$V_{GS} = -20\text{V}$ , $V_{DS} = 0\text{V}$

### ON Characteristics

 $T_A = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
$I_{DSS}$	Saturated Drain-to-Source Current	200	--	--	mA	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$
$R_{DS(ON)}$	Static Drain-to-Source On-Resistance	--	10	15	$\Omega$	$V_{GS} = 0\text{V}$ , $I_D = 200\text{mA}$ <sup>[3]</sup>
$V_{GS(OFF)}$	Gate-to-Source Cut-off Voltage	-7	--	-5	V	$V_{DS} = 3\text{V}$ , $I_D = 8\mu\text{A}$
gfs	Forward Transconductance	--	0.24	--	S	$V_{DS} = 10\text{V}$ , $I_D = 100\text{mA}$

### Dynamic Characteristics

Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
$C_{ISS}$	Input Capacitance	--	12.8	--	pF	$V_{GS} = -10\text{V}$ $V_{DS} = 25\text{V}$ $f = 1.0\text{MHz}$
$C_{OSS}$	Output Capacitance	--	5.4	--		
$C_{RSS}$	Reverse Transfer Capacitance	--	3.3	--		
$Q_G$	Total Gate Charge	--	3	--	nC	$V_{GS} = -10\text{V} \sim 0\text{V}$ $V_{DS} = 75\text{V}$ , $I_D = 200\text{mA}$
$Q_{GS}$	Gate-to-Source Charge	--	0.23	--		
$Q_{GD}$	Gate-to-Drain (Miller) Charge	--	1.1	--		

### Resistive Switching Characteristics

Essentially independent of operating temperature

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
$t_{d(ON)}$	Turn-on Delay Time	--	7	--	ns	$V_{GS} = -10\text{V} \sim 0\text{V}$ $V_{DD} = 75\text{V}$ , $I_D = 200\text{mA}$ $R_G = 20\Omega$
$t_{rise}$	Rise Time	--	16	--		
$t_{d(OFF)}$	Turn-off Delay Time	--	25	--		
$t_{fall}$	Fall Time	--	120	--		

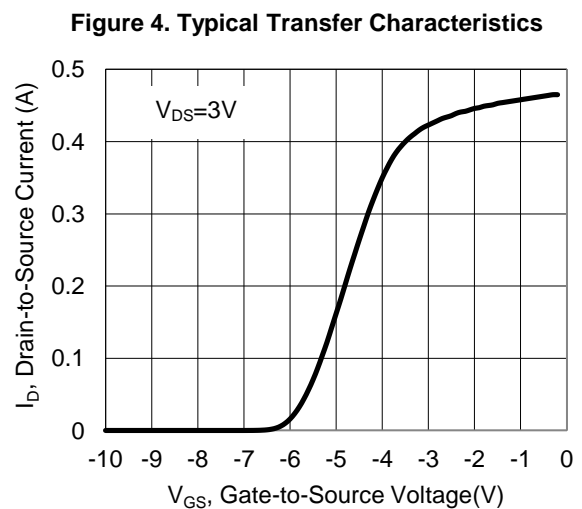
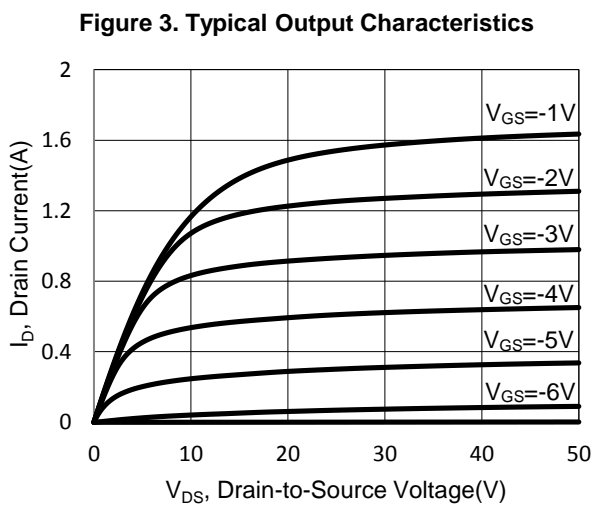
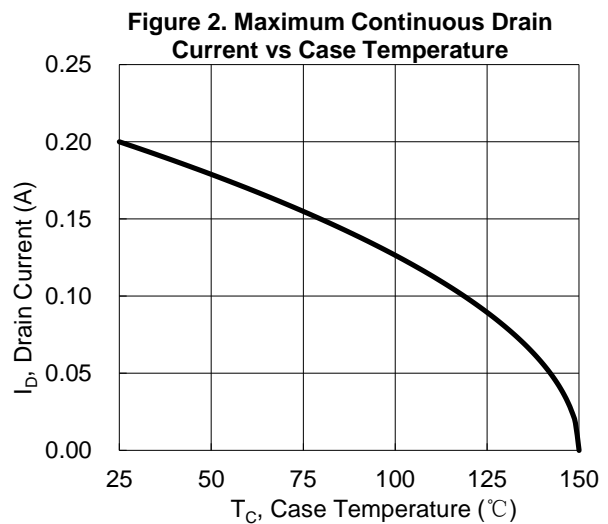
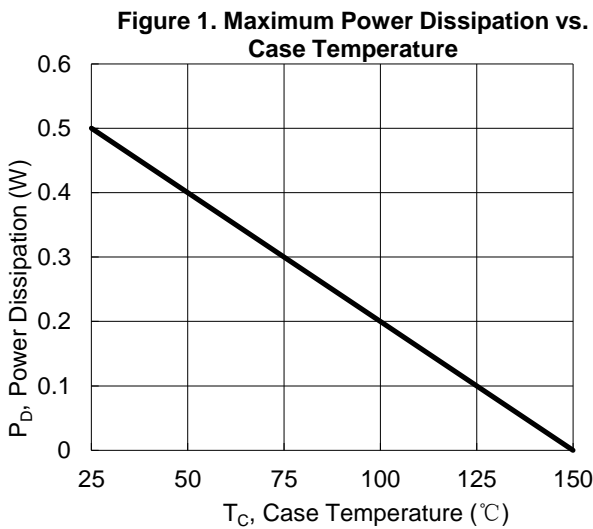
**Source-Drain Diode Characteristics**

$T_A=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Min	Typ.	Max.	Units	Test Conditions
$V_{SD}$	Diode Forward Voltage	--	--	1.2	V	$I_{SD}=200\text{ mA}$ , $V_{GS} = -15\text{ V}$

**NOTE:**

- [1]  $T_J=+25^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$
- [2] Repetitive rating, pulse width limited by maximum junction temperature.
- [3] Pulse width  $\leq 380\mu\text{s}$ ; duty cycle  $\leq 2\%$ .



## Package Dimensions

